

Ordering number : ENN7018

P-Channel Silicon MOSFET

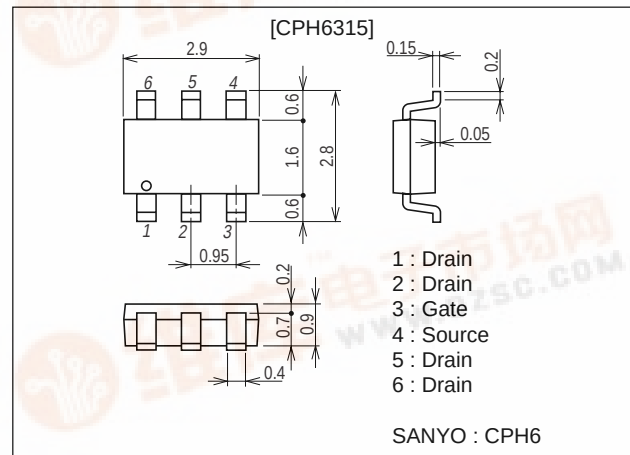
SANYO**CPH6315****High-Speed Switching Applications****Features**

- Low ON-resistance.
- High-speed switching.
- 2.5V drive.

Package Dimensions

unit : mm

2151A

**Specifications****Absolute Maximum Ratings** at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		-20	V
Gate-to-Source Voltage	V _{GSS}		±10	V
Drain Current (DC)	I _D		-3	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	-12	A
Allowable Power Dissipation	P _D	Mounted on a ceramic board (1200mm²X0.8mm)	1.6	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V(BR) _{DSS}	I _D =-1mA, V _{GS} =0	-20			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =-20V, V _{GS} =0			-10	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GSS} =±8V, V _{DS} =0			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =-10V, I _D =-1mA	-0.3		-1.4	V
Forward Transfer Admittance	y _{fs}	V _{DS} =-10V, I _D =-1A	2.1	3		S
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =-1A, V _{GS} =-4V		115	150	mΩ
	R _{DS(on)2}	I _D =-0.5A, V _{GS} =-2.5V		145	210	mΩ

Marking : JR

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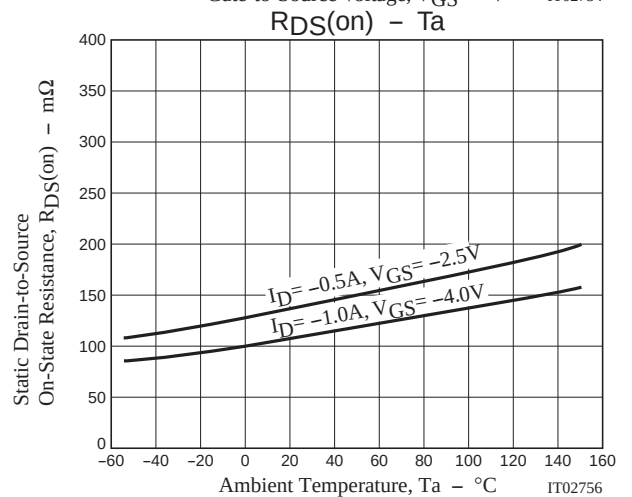
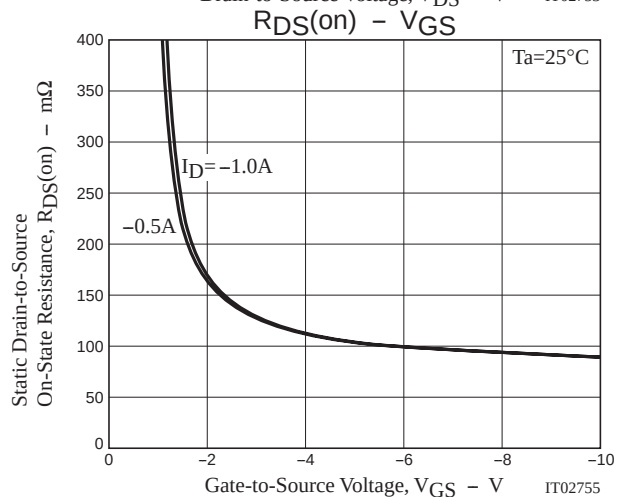
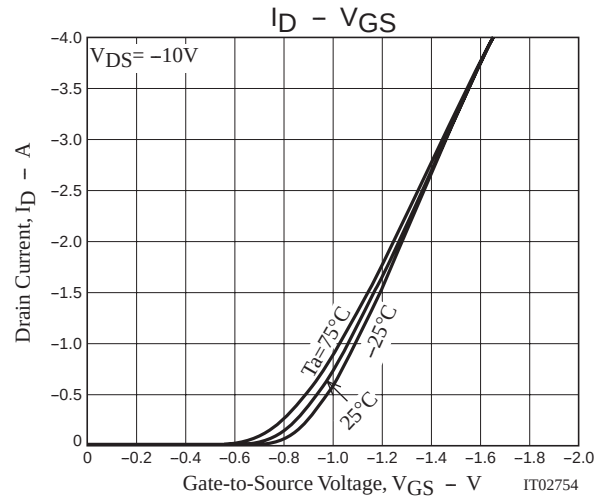
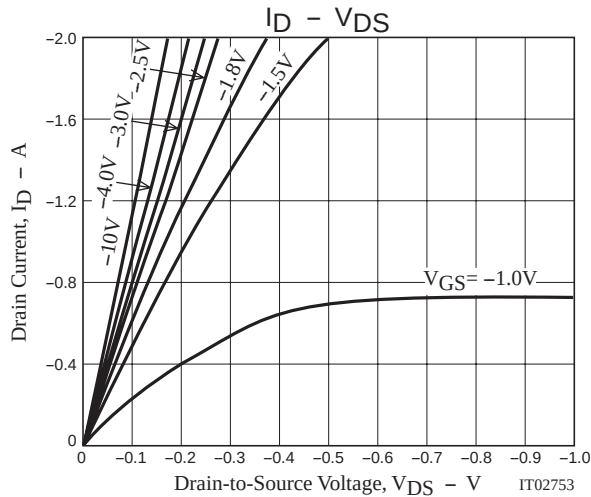
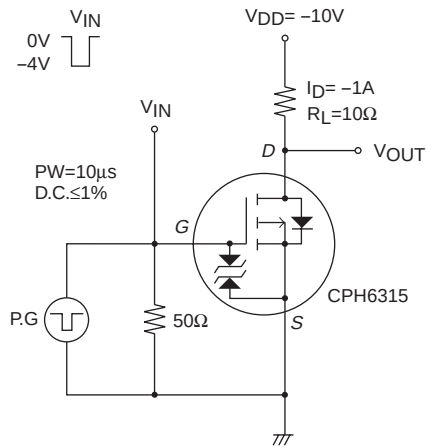
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CPH6315

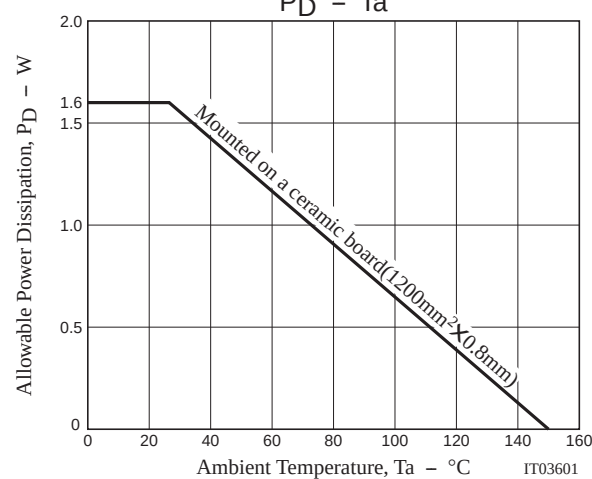
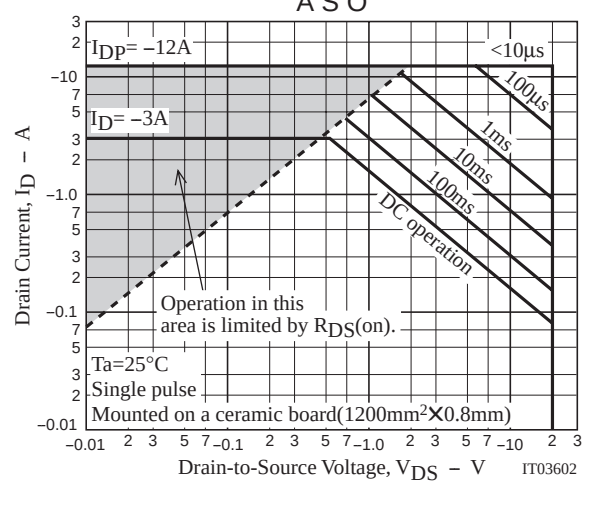
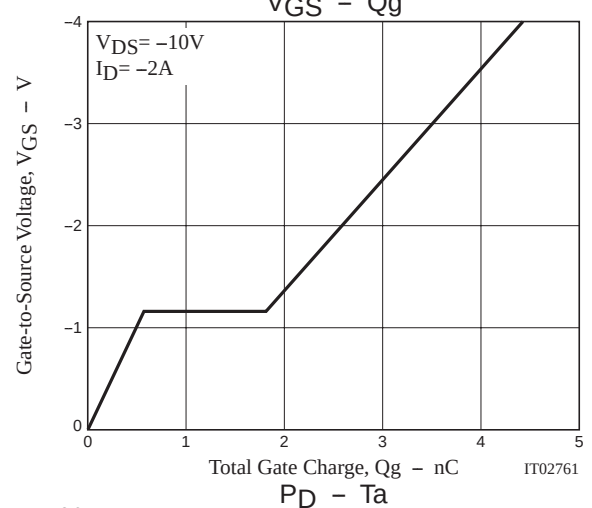
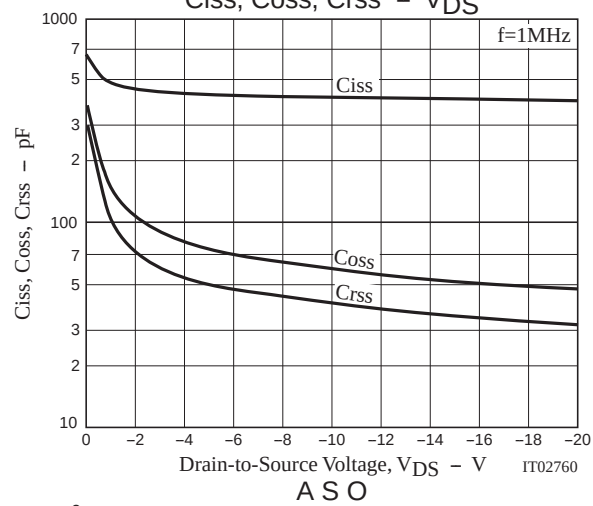
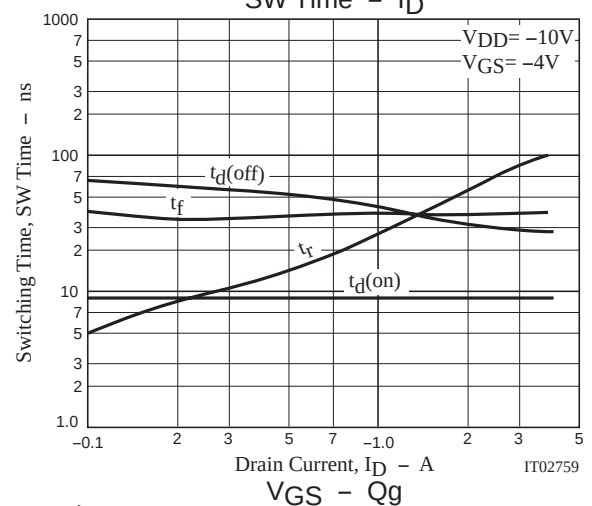
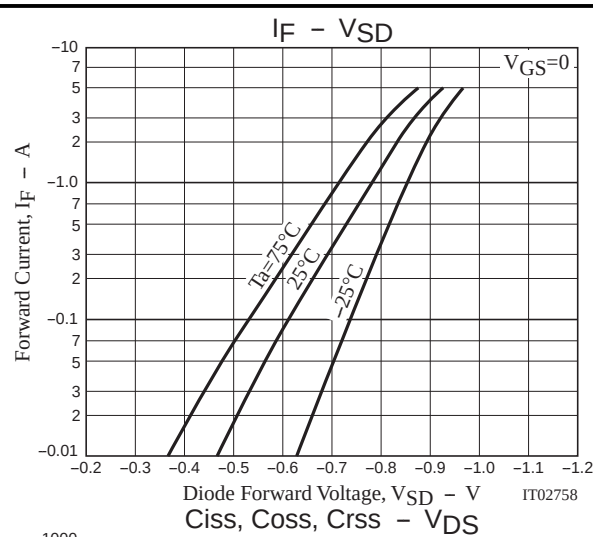
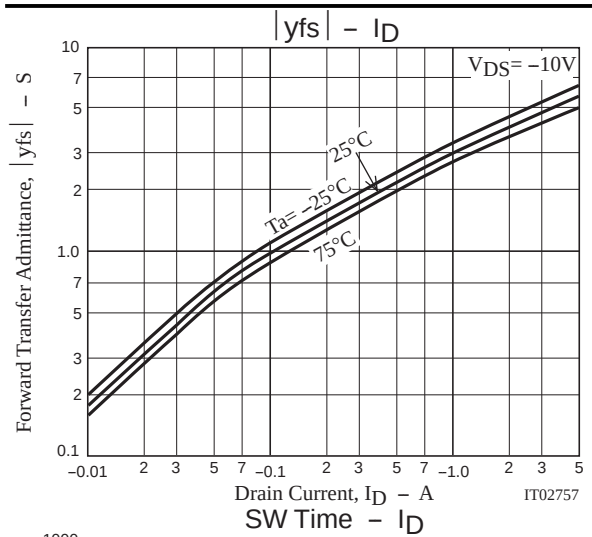
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	C_{iss}	$V_{DS}=-10V, f=1MHz$		410		pF
Output Capacitance	C_{oss}	$V_{DS}=-10V, f=1MHz$		60		pF
Reverse Transfer Capacitance	C_{rss}	$V_{DS}=-10V, f=1MHz$		40		pF
Turn-ON Delay Time	$t_d(on)$	See specified Test Circuit.		9		ns
Rise Time	t_r	See specified Test Circuit.		27		ns
Turn-OFF Delay Time	$t_d(off)$	See specified Test Circuit.		42		ns
Fall Time	t_f	See specified Test Circuit.		38		ns
Total Gate Charge	Q_g	$V_{DS}=-10V, V_{GS}=-4V, I_D=-2A$		4.5		nC
Gate-to-Source Charge	Q_{gs}	$V_{DS}=-10V, V_{GS}=-4V, I_D=-2A$		0.6		nC
Gate-to-Drain "Miller" Charge	Q_{gd}	$V_{DS}=-10V, V_{GS}=-4V, I_D=-2A$		1.2		nC
Diode Forward Voltage	V_{SD}	$I_S=-2A, V_{GS}=0$		-0.88	-1.2	V

Switching Time Test Circuit



CPH6315



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